UNR32A3

Silicon NPN epitaxial planar transistor

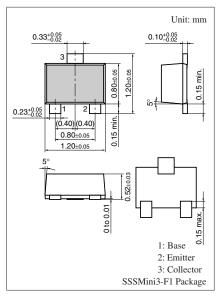
For digital circuits

Features

- Suitable for high density package and downsizing of the equipment
- Contribute to low power consumption

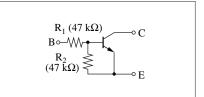
Parameter		Symbol	Rating	Unit					
Rating	Collector to base voltage	V _{CBO}	50	V					
of	Collector to emitter voltage	V _{CEO}	50	V					
element	Collector current	I _C	80	mA					
Overall	Total power dissipation	P _T	100	mW					
	Junction temperature	Tj	125	°C					
	Storage temperature	T _{stg}	-55 to +125	°C					

Absolute Maximum Ratings $T_a = 25^{\circ}C$



Marking Symbol: FN

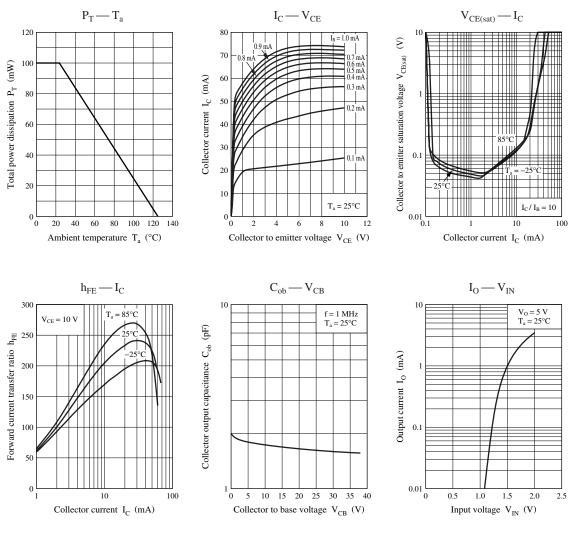
Internal Connection

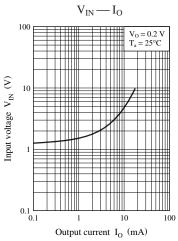


Parameter	Symbol	Conditions	Min	Тур	Мах	Unit
Collector to base voltage	V _{CBO}	$I_{\rm C} = 10 \ \mu A, \ I_{\rm E} = 0$	50			V
Collector to emittter voltage	V _{CEO}	$I_{\rm C} = 2 \text{ mA}, I_{\rm B} = 0$	50			V
Collector cutoff current	I _{CBO}	$V_{CB} = 50 \text{ V}, I_E = 0$			0.1	μΑ
	I _{CEO}	$V_{CE} = 50 \text{ V}, I_B = 0$			0.5	
Emitter cutoff current	I _{EBO}	$V_{EB} = 6 V, I_C = 0$			0.1	mA
Forward current transfer ratio	h_{FE}	$V_{CE} = 10 \text{ V}, I_C = 5 \text{ mA}$	80			—
Collector to emitter saturation voltage	V _{CE(sat)}	$I_{\rm C} = 10 \text{ mA}, I_{\rm B} = 0.3 \text{ mA}$			0.25	V
High level output voltage	V _{OH}	$V_{CC} = 5 \text{ V}, V_{B} = 0.5 \text{ V}, R_{L} = 1 k\Omega$	4.9			V
Low level output voltage	V _{OL}	$V_{CC} = 5 \text{ V}, V_{B} = 3.5 \text{ V}, R_{L} = 1 k\Omega$			0.2	V
Input resistance	R ₁		-30%	47	+30%	kΩ
Resistance ratio	R ₁ / R ₂		0.8	1.0	1.2	_
Gain bandwidth product	f _T	$V_{CB} = 10 \text{ V}, I_E = -2 \text{ mA}, f = 200 \text{ MHz}$		150		MHz

Electrical Characteristics $T_a = 25^{\circ}C \pm 3^{\circ}C$

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